

Materials for Quantum Technologies: a Roadmap for Spin and Topology

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Qubit type	Spin Coherence time	Single qubit gate operation time	Single qubit gate error
Si and Ge gate-defined QDs	Si electron (T_2^{CPMG}): 28 ms ¹ Ge electron (T_2^{Echo}): 0.158 ms ²	Si: 2.5 ns ³ Ge: 0.41 ns ⁴	Si: 0.04% ⁵ Ge: 0.01% ⁶
Donor based Si	Electron (T_2^{CPMG}): 0.56 s ⁷ ; Nuclear (T_2^{CPMG}): 36 s ⁸	Electron: 100 ns ⁸ Nuclear: 25 μ s ⁹	—
III-V QDs	Electron (T_2^{CPMG}): 100 μ s ¹⁰ Nuclear (T_2): 20 ms ¹¹	Electron: 1 ps ¹² Nuclear: 1 μ s ¹¹ Electro-nuclear: 100 ns ¹³	Electron: 1% ¹⁰ Nuclei: 3% ¹¹
NV centre in diamond	Electron (T_2^{CPMG}): 0.6 s ¹⁴ Nuclear (T_2^*): 1.9 mins ¹⁵	Electron: 10 ns; ¹⁶ Nuclear: 50 μ s ¹⁶	Electron: 0.01% ¹⁷ Nuclei: 0.09% ¹⁸
G4 defects in diamond	Electron (T_2^{CPMG}): 0.3 ms ¹⁹ Nuclear (T_2^{XY8}): 2 s ¹⁹	Electron: 125 ns ²⁰ Nuclear: 50 μ s ¹⁹	Electron: 0.1% ¹⁹ Nuclear: 2% ¹⁹
Defects in SiC	Electron (T_2^{CPMG}): 5 s ²¹ Nuclear (T_2^*): 9.9 ms ²²	Electron: ~100 ns ²³ Nuclear: 12.7 μ s ²⁴	Electron: 0.02% ²⁴ Nuclear: 3.3% ²²
Defects in hBN	Electronic Ensemble (T_2^{CPMG}): 4 μ s ²⁵ Electronic single (T_2^{CPMG}): 1 μ s ²⁶	Electron: 50 ns ²⁶	—

Table S1: Semiconducting spin qubits and their individual figures of merit. CPMG: Carr-Purcell-Meiboom-Gill, Echo: Hahn-Echo pulse sequences. T_2^* : Inhomogeneous dephasing time measured by Ramsey.

Qubit type	Coherence time (T2)	Single qubit gate operation time	Size	Operational temperature	Initialization and readout efficiency
Skymion (helicity) ^{27,28}	—	180 fs	3 nm	Up to 3.8 K	—
Skymion (helicity) ²⁹	~ 1 μ s	—	—	Up to 2.5 K	Electric field of 296 mV/ μ m
Skymion (presence) ³⁰	—	3.2 ns	—	—	—
Meron (polarity) ³¹	—	1 ps	3 nm	Up to 3 K	—
Domain wall (chirality) ³²	~ 1 μ s	0.1 ns	5 nm	Up to 100 mK	—

Table S 2: Comparison of critical FOMs for the development of skyrmion-based quantum technologies, also including the corresponding values for meron- and domain wall-based approaches.

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